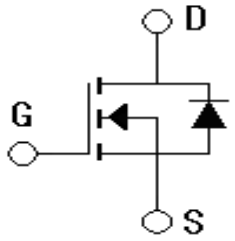
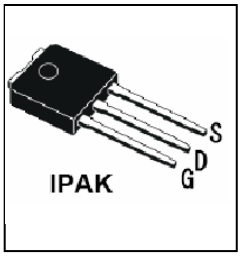
JCS8HN60C

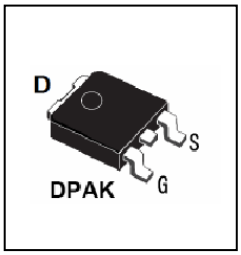
主要参数 MAIN CHARACTERISTICS

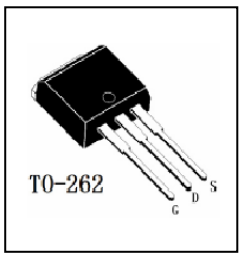
I_D	8.0 A
V_{DSS}	600 V
Rdson-max （@Vgs=10V）	1.6Ω
Qg-typ	32 nC

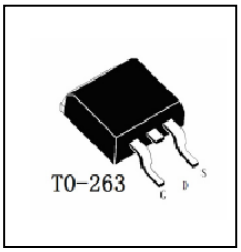
封装 **Package**

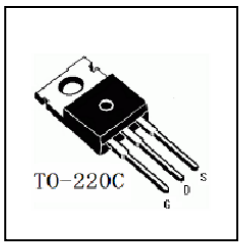


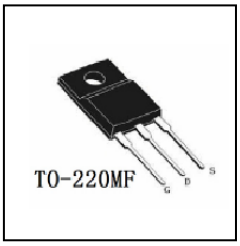












用途

- 高频开关电源
- 电子镇流器
- LED 电源

APPLICATIONS

- High frequency switching mode power supply
- Electronic ballast
- LED power supply

产品特性

- 低栅极电荷
- 低 C_{rss} (典型值 14pF)
- 开关速度快
- 产品全部经过雪崩测试
- 高抗 dv/dt 能力
- RoHS 产品

FEATURES

- Low gate charge
- Low C_{rss} (typical 14pF)
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product

订货信息 ORDER MESSAGE

订 货 型 号 Order codes	印 记 Marking	封 装 Package	无卤素 Halogen Free	包 装 Packaging	器件重量 Device Weight
JCS8HN60VC-O-V-N-B	JCS8HN60VC	IPAK	否 NO	条管 Tube	0.35 g(typ)
JCS8HN60RC-O-R-N-B	JCS8HN60RC	DPAK	否 NO	条管 Tube	0.30 g(typ)
JCS8HN60RC-O-R-N-A	JCS8HN60RC	DPAK	否 NO	编带 Reel	0.30 g(typ)
JCS8HN60CC-O-C-N-B	JCS8HN60CC	TO-220C	否 NO	条管 Tube	2.15 g(typ)
JCS8HN60FC-O-F-N-B	JCS8HN60FC	TO-220MF	否 NO	条管 Tube	2.20 g(typ)
JCS8HN60SC-O-F-N-B	JCS8HN60SC	TO-263	否 NO	条管 Tube	1.37 g(typ)
JCS8HN60SC-O-F-N-A	JCS8HN60SC	TO-263	否 NO	编带 Reel	1.37 g(typ)
JCS8HN60BC-O-F-N-B	JCS8HN60BC	TO-262	否 NO	条管 Tube	1.71 g(typ)

绝对最大额定值 ABSOLUTE RATINGS (Tc=25℃)

项 目 Parameter	符 号 Symbol	数 值 Value		单位 Unit
		JCS8HN60 CC/SC/BC/VC/RC	JCS8HN60FC	
最高漏极－源极直流电压 Drain-Source Voltage	V_{DSS}	600	600	V
连续漏极电流 Drain Current -continuous	I_D T=25℃	7.0	7.0*	A
	T=100℃	4.6	4.6*	A
最大脉冲漏极电流（注 1） Drain Current - pulse （note 1）	I_{DM}	28	28*	A
最高栅源电压 Gate-Source Voltage	V_{GSS}	±30		V
单脉冲雪崩能量（注 2） Single Pulsed Avalanche Energy（note 2）	E_{AS}	420		mJ
雪崩电流（注 1） Avalanche Current（note 1）	I_{AR}	7.0		A
重复雪崩能量（注 1） Repetitive Avalanche Energy（note 1）	E_{AR}	12.8		mJ
二极管反向恢复最大电压变化速率（注 3） Peak Diode Recovery dv/dt （note 3）	dv/dt	4.5		V/ns
耗散功率 Power Dissipation	P_D T_C=25℃	120	40	W
	-Derate above 25℃	1.04	0.31	W/℃
最高结温及存储温度 Operating and Storage Temperature Range	T_J，T_{STG}	-55～+150		℃
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T_L	300		℃

*漏极电流由最高结温限制

*Drain current limited by maximum junction temperature

电特性 ELECTRICAL CHARACTERISTICS

项　　目 Parameter	符　号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最 大 Max	单 位 Units
关态特性 Off –Characteristics						
漏－源击穿电压 Drain-Source Voltage	BV_{DSS}	I_D=250μA, V_{GS}=0V	600	-	-	V
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	$\Delta BV_{DSS}/\Delta T_J$	I_D=250μA, referenced to 25℃	-	0.65	-	V/℃
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=600V,V_{GS}=0V, T_C=25℃	-	-	10	μA
		V_{DS}=480V, T_C=125℃	-	-	100	μA
正向栅极体漏电流 Gate-body leakage current, forward	I_{GSSF}	V_{DS}=0V, V_{GS} =30V	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	I_{GSSR}	V_{DS}=0V, V_{GS} =-30V	-	-	-100	nA
通态特性 On-Characteristics						
阈值电压 Gate Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS} , I_D=250μA	2.0	-	4.0	V
静态导通电阻 Static Drain-Source On-Resistance	$R_{DS(ON)}$	V_{GS} =10V , I_D=3.5A	-	1.26	1.6	Ω
正向跨导 Forward Transconductance	g_{fs}	V_{DS} = 40V, I_D=3.5A（note 4）	-	5.6	-	S
动态特性 Dynamic Characteristics						
输入电容 Input capacitance	C_{iss}	V_{DS}=25V, V_{GS} =0V, f=1.0MHz	-	1620	1890	pF
输出电容 Output capacitance	C_{oss}		-	125	170	pF
反向传输电容 Reverse transfer capacitance	C_{rss}		-	14	20	pF

电特性 ELECTRICAL CHARACTERISTICS

开关特性 Switching Characteristics						
延迟时间 Turn-On delay time	$t_d(on)$	V_{DD}=300V,I_D=7A,R_G=25Ω （note 4，5）	-	11	31	ns
上升时间 Turn-On rise time	t_r		-	35	80	ns
延迟时间 Turn-Off delay time	$t_d(off)$		-	46	95	ns
下降时间 Turn-Off Fall time	t_f		-	40	92	ns
栅极电荷总量 Total Gate Charge	Q_g	V_{DS} =480V , I_D=7A V_{GS} =10V （note 4，5）	-	32	41	nC
栅－源电荷 Gate-Source charge	Q_{gs}		-	6	-	nC
栅－漏电荷 Gate-Drain charge	Q_{gd}		-	15	-	nC
漏－源二极管特性及最大额定值 **Drain-Source Diode Characteristics and Maximum Ratings**						
正向最大连续电流 Maximum Continuous Drain -Source Diode Forward Current	I_S		-	-	7.0	A
正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current	I_{SM}		-	-	28	A
正向压降 Drain-Source Diode Forward Voltage	V_{SD}	V_{GS}=0V, I_S=7.0A	-	-	1.4	V
反向恢复时间 Reverse recovery time	t_{rr}	V_{GS}=0V, I_S=7.0A dI_F/dt=100A/μs (note 4)	-	345	-	ns
反向恢复电荷 Reverse recovery charge	Q_{rr}		-	3.2	-	μC

热特性 THERMAL CHARACTERISTIC

项 目 **Parameter**	符 号 **Symbol**	最大 **Max** JCS8HN60VC/RC/CC/SC/BC	最大 **Max** JCS8HN60FC	单 位 **Unit**
结到管壳的热阻 Thermal Resistance, Junction to Case	Rth(j-c)	1.04	3.2	℃/W
结到环境的热阻 Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	62.5	62.5	℃/W

注释：

1：脉冲宽度由最高结温限制

2：L=14mH, I_{AS}=7.0A, V_{DD}=50V, R_G=25 Ω,起始结温 T_J=25℃

3：I_{SD}≤6.0A,di/dt≤300A/μs,VDD≤BV_{DSS},起始结温 T_J=25℃

4：脉冲测试：脉冲宽度≤300μs,占空比≤2%

5：基本与工作温度无关

Notes:

1：Pulse width limited by maximum junction temperature

2：L=14mH, I_{AS}=7.0A, V_{DD}=50V, R_G=25 Ω,Starting T_J=25℃

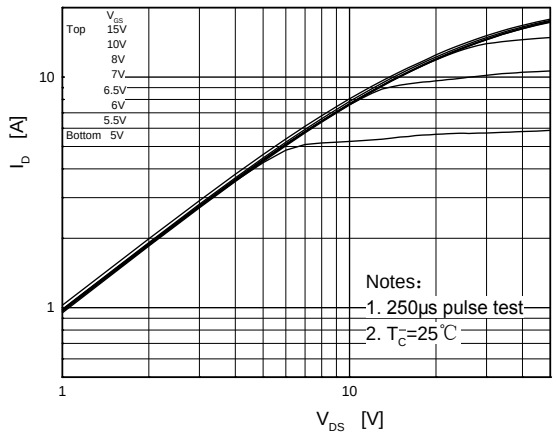
3：I_{SD}≤6.0A,di/dt≤300A/μs,VDD≤BV_{DSS}, Starting T_J=25℃

4：Pulse Test：Pulse Width ≤300μs,Duty Cycle≤2%

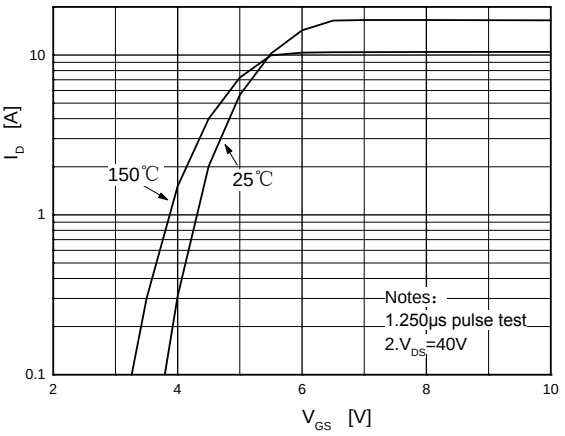
5：Essentially independent of operating temperature

特征曲线 ELECTRICAL CHARACTERISTICS (curves)

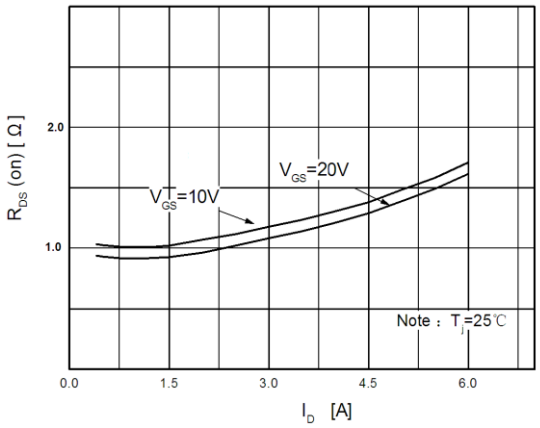
On-Region Characteristics



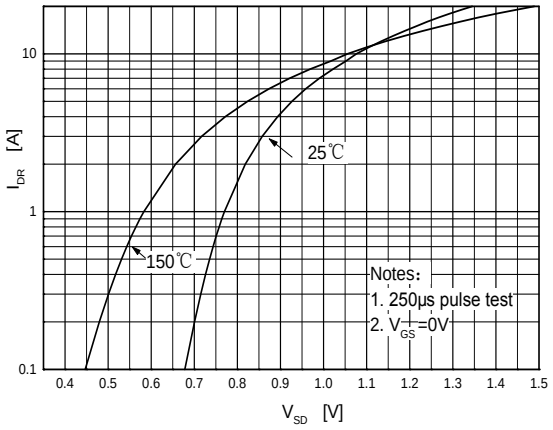
Transfer Characteristics



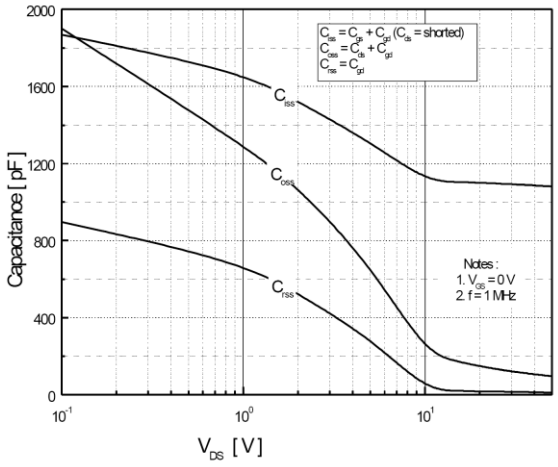
On-Resistance Variation vs. Drain Current and Gate Voltage



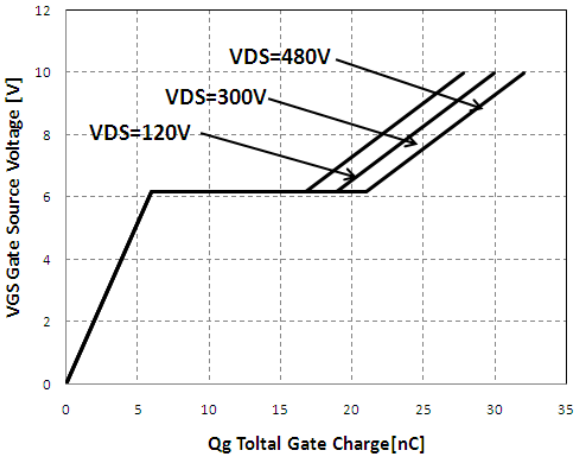
Body Diode Forward Voltage Variation vs. Source Current and Temperature



Capacitance Characteristics

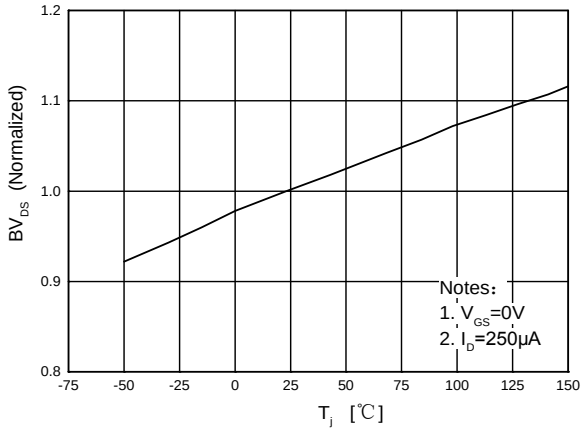


Gate Charge Characteristics

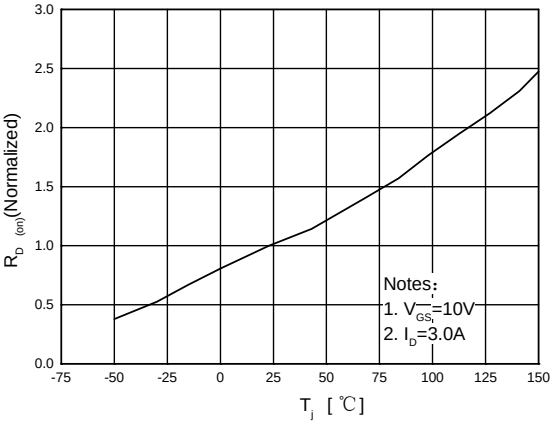


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

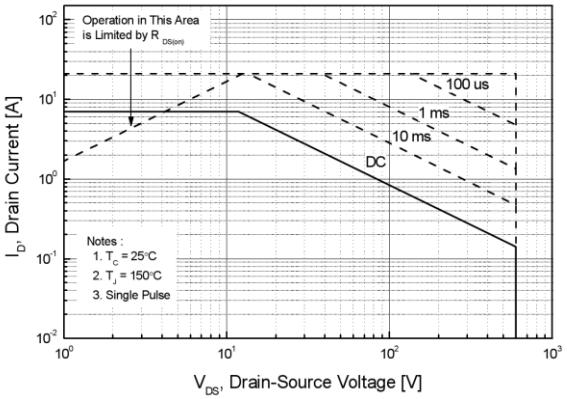
Breakdown Voltage Variation vs. Temperature



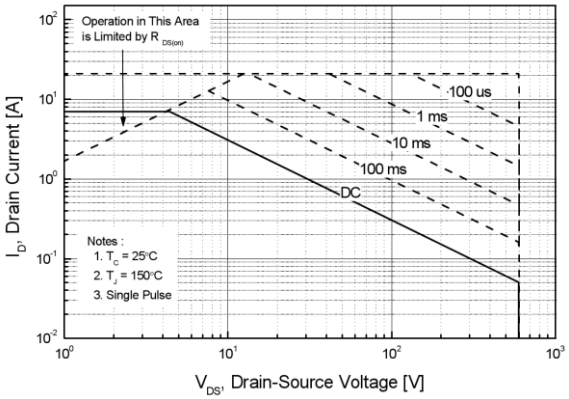
On-Resistance Variation vs. Temperature



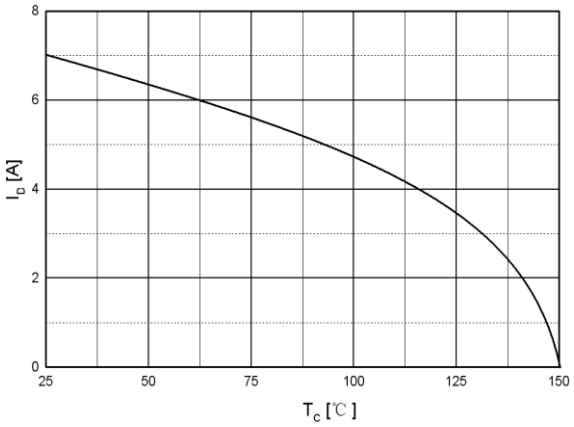
Maximum Safe Operating Area For JCS8HN60CC/SC/BC/RC/VC



Maximum Safe Operating Area For JCS8HN60FC

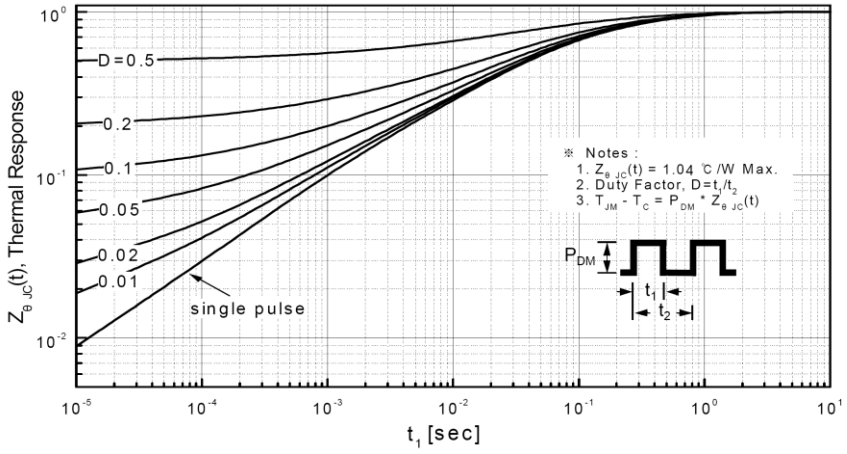


Maximum Drain Current vs. Case Temperature

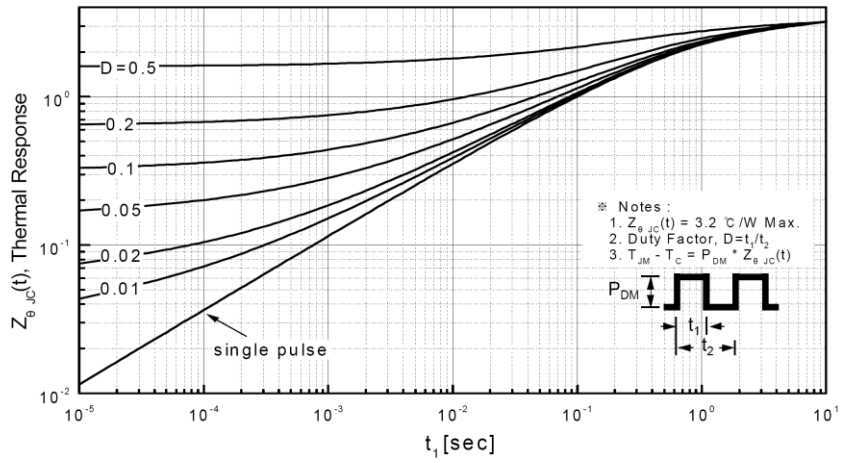


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

Transient Thermal Response Curve For JCS8HN60CC/SC/BC/RC/VC



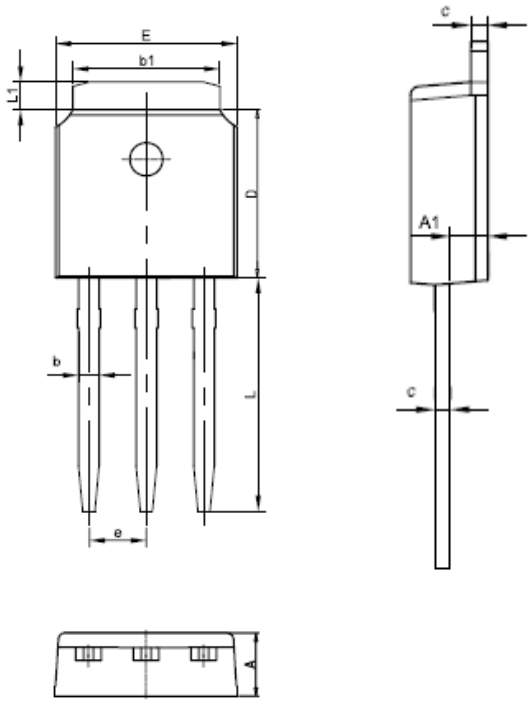
Transient Thermal Response Curve For JCS8HN60FC



外形尺寸 **PACKAGE MECHANICAL DATA**

IPAK

单位 Unit：mm

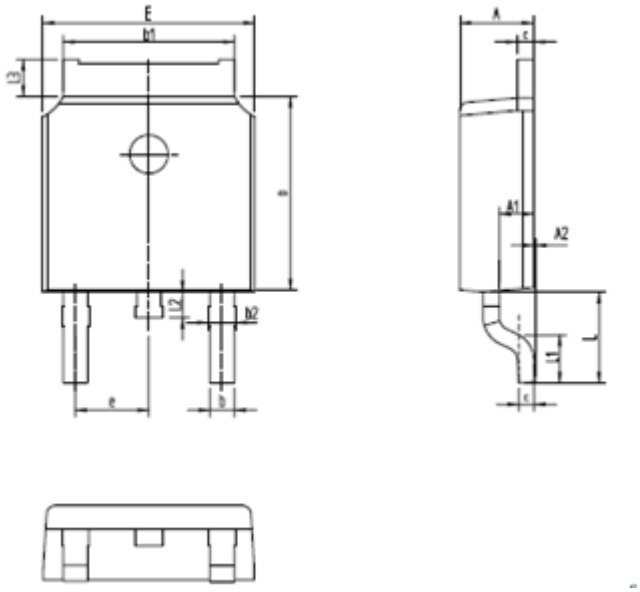


SYMBOL	MM	
	MIN	MAX
A	2.1	2.5
A1	0.87	1.27
b	0.63	0.93
b1	5.13	5.53
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
L	9.10	9.70
e	2.286BSC	
L1	0.82	1.22

外形尺寸 PACKAGE MECHANICAL DATA

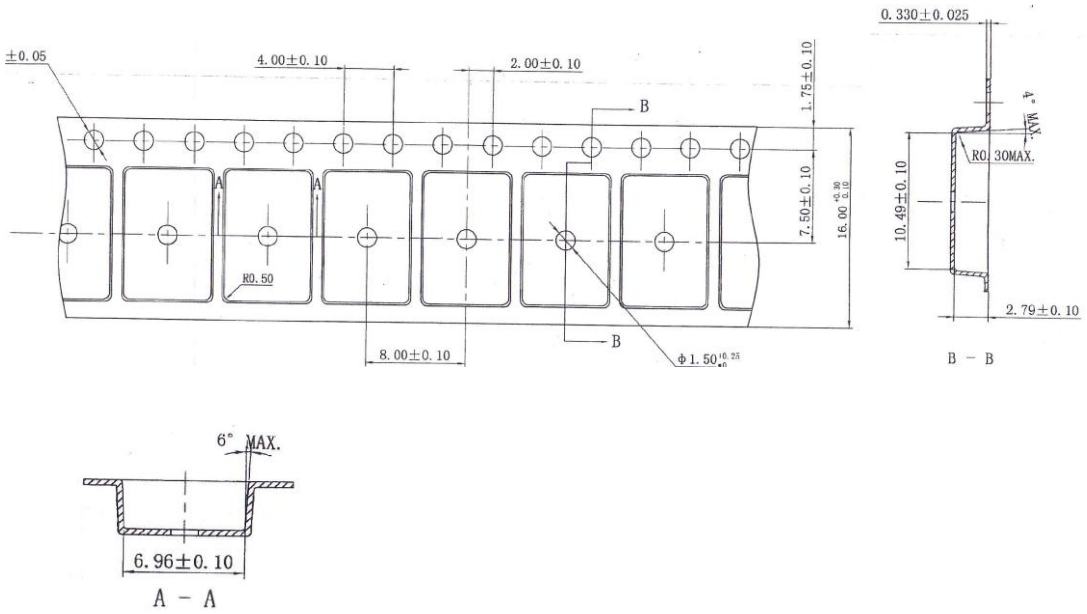
DPAK

单位 Unit：mm



SYMBOL	mm	
	MIN	MAX
A	2.16	2.41
A1	0.97	1.17
A2	0.00	0.15
b	0.63	0.93
b1	5.13	5.53
b2	0.66	0.96
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
e	2.286BSC	
L	2.50	3.30
L1	1.20	1.80
L2	0.60	1.00
L3	0.85	1.30

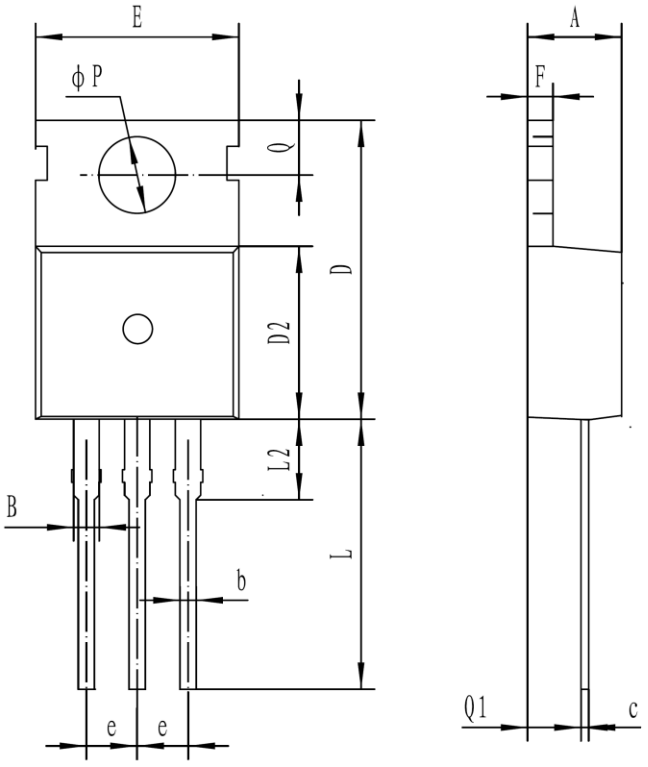
编带 REEL



外形尺寸 PACKAGE MECHANICAL DATA

TO-220C

单位 Unit：mm

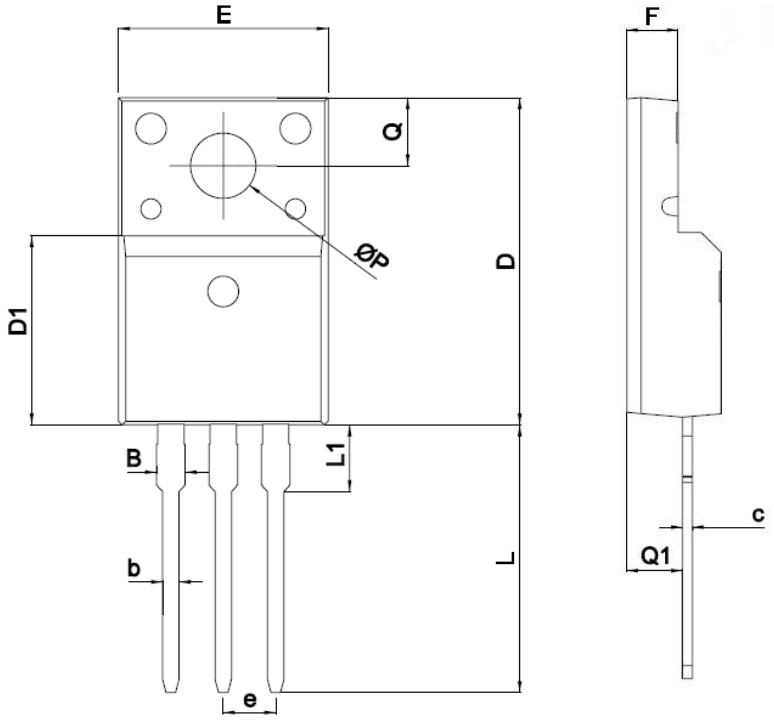


符号 symbol	MIN	MAX
A	4.30	4.70
B	1.10	1.40
b	0.70	0.95
c	0.40	0.65
D	15.20	16.20
D2	9.00	9.40
E	9.70	10.10
e	2.39	2.69
F	1.25	1.40
L	12.60	13.60
L2	2.80	3.20
Q	2.60	3.00
Q1	2.20	2.60
P	3.50	3.80

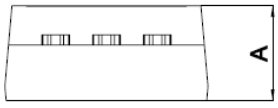
外形尺寸 **PACKAGE MECHANICAL DATA**

TO-220MF

单位 Unit：mm



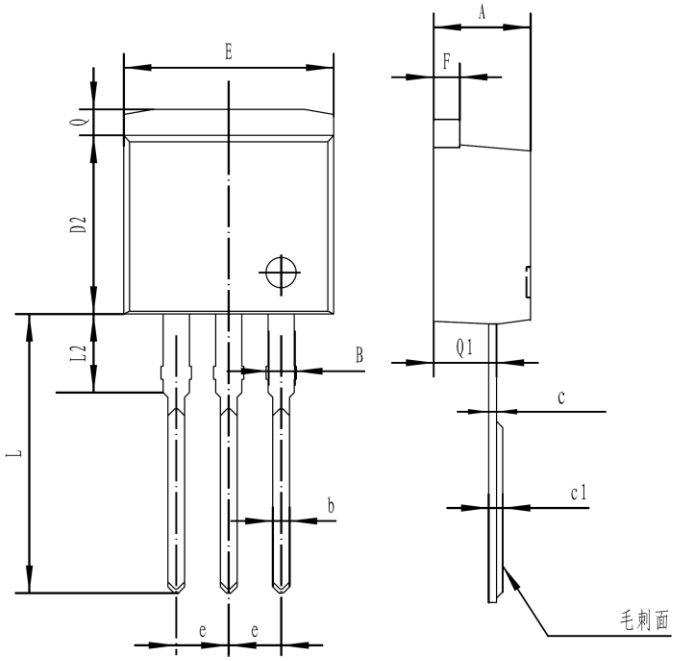
SYMBOL	mm	
	MIN	MAX
A	4.5	4.9
B		1.47
b	0.7	0.9
c	0.45	0.60
D	15.67	16.07
D1	9.04	9.20
e	2.54TYPE	
E	9.96	10.36
F	2.34	2.74
L	12.58	13.38
L1	3.13	3.33
Q	3.2	3.4
Q1	2.56	2.96
ΦP	3.08	3.28



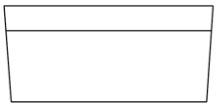
外形尺寸 **PACKAGE MECHANICAL DATA**

TO-262

单位 Unit：mm



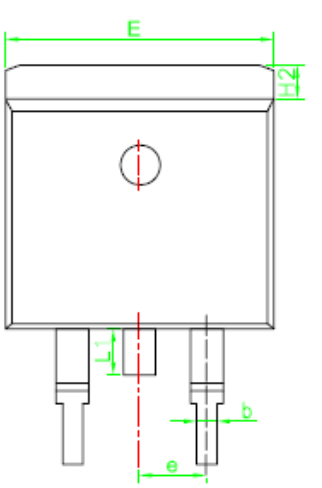
符号 symbol	MIN	MAX
A	4.40	4.90
B	1.10	1.40
b	0.70	0.95
c	0.30	0.60
c1	0.33	0.63
D2	8.20	9.20
E	9.60	10.50
e	2.39	2.69
F	1.20	1.35
L	13.11	14.61
L2	3.55	4.05
Q	1.10	1.40
Q1	2.65	2.85



外形尺寸 PACKAGE MECHANICAL DATA

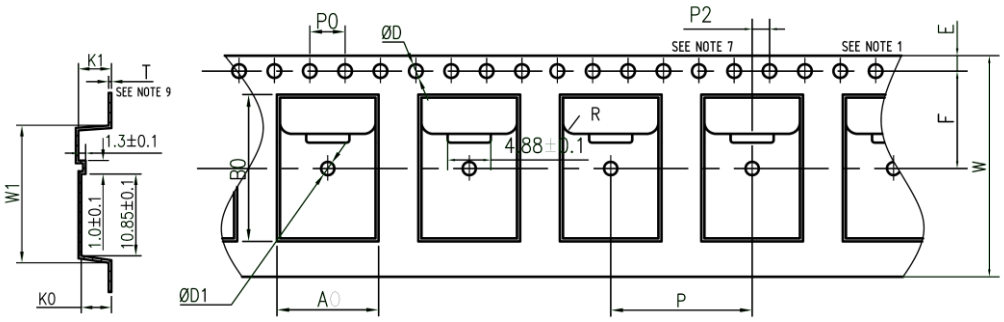
TO-263

单位 Unit：mm



SYMBOL	MM	
	MIN	MAX
A	4.30	4.80
A1	1.12	1.42
A2	2.54	2.84
b	0.67	1.00
c	0.29	0.52
D1	8.40	9.00
E	9.80	10.46
e	2.54BSC	
H	14.00	16.00
H2	1.12	1.45
L	1.50	3.10
L1	1.45	1.70

编带 REEL



NOTES

1. 10 SPROCKET HOLE PITCH CUMULATIVE TOLEANCE 0.2mm;
   任意10个传输孔间距累积误差0.2mm;
2. MATERIAL: BLACK CONDUCTIVE POLYSTYRENE;
   材料：黑色防静电聚苯乙烯;
3. DEMENSIONS ARE IN mm (UNLESS OTHERWISE SPECIFIEED);
   除非特别标注，尺寸单位为毫米;
4. K0 MEASURED FROM A PLANE ON THE INSIDE BOTTOM OF THE POCKET TO THE TOP SURFACE ON THE CARRIER;
   K0是从凹槽底部上表面到载带顶面的测量尺寸;
5. A0 AND B0 MEASURED ON A PLANE 0.30mm ABOVE THE BOTTOM OF THE POCKET;
   从凹槽底部上方测量A0和B0的平面度是0.30mm;
6. SURFACE RESISTIVITY IS BETWEEN 1×10E6 TO 1×10E10 OHMS/SQUARE;
   表面阻抗1X10e6~1X10e10Ω/口;
7. Allowable Camber to be 1 mm/100 mm
   载带100mm以内，弯曲度不可超过1mm。

外观	尺寸
P0	4.0±0.1
P2	2.0±0.1
P	16.0±0.1
T	0.35±0.05
K0	4.85±0.1
B0	16.3±0.1

外观		尺寸
W		24.0 ±0.3
A0		10.8±0.2
E		1.75±0.1
F		11.5±0.1
D		1.55±0.05
D1		1.5±0.1
W1	规格1	16.9±0.1
	规格2	17.2±0.1

注意事项

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3.在电路设计时请不要超过器件的绝对最大额定值，否则会影响整机的可靠性。

4.本说明书如有版本变更不另外告知

NOTE

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